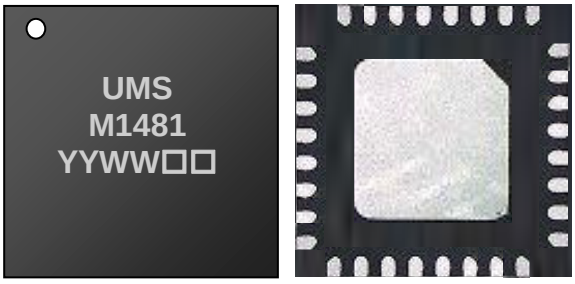
6-9GHz Direct Quadrature Modulator

GaAs Monolithic Microwave IC in SMD leadless package

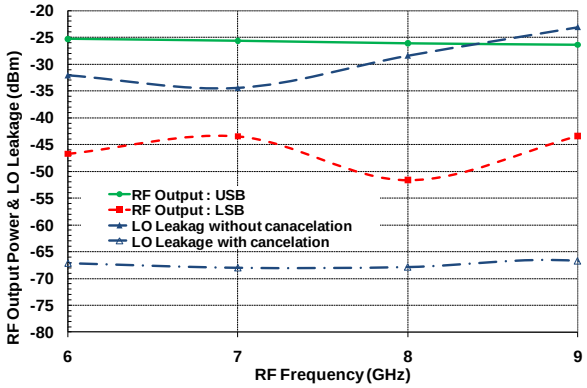
Description

The CHM1481-QFG is a 6-9GHz direct quadrature modulator packaged integrates a double-balanced mixer (LO suppression and Image Rejection) and a LO buffer. It can be used for both LSB and USB configurations.
The circuit is mainly dedicated to Point to Point and Point to Multi-Point systems and also well suited for a wide range of microwave applications.
The circuit is m²anufactured with a pHEMT process, 0.5µm gate length.
It is supplied in RoHS compliant SMD package.



Main Features

- RF Broadband performances: 6-9GHz
- Input Broadband bandwidth: DC-250MHz
- 20dBc Image Rejection
- -30dBm LO leakage without cancelation
- -65dBm LO leakage with cancelation
- 0dBm LO input Power
- 32L-QFN5x5
- MSL2



Main Electrical Characteristics

Tamb.= +25°C

Symbol	Parameter	Min	Typ	Max	Unit
F_{RF}	Output RF Frequency range	6		9	GHz
F_{LO}	LO Frequency range	6		9	GHz
F_{IF}	Base band bandwidth	DC		250	MHz
P_{RF}	Output Power		-26		dBm

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Electrical Characteristics

Tamb.= +25°C, VD1 = VD2 = VD3 = +4V

Symbol	Parameter	Min	Typ	Max	Unit
F_{RF}	RF Frequency range	6		9	GHz
F_{LO}	LO Frequency range	6		9	GHz
F_{BB}	Baseband input 1dB bandwidth	DC		250	MHz
P_{RF}	Output Power (1)		-26		dBm
P_{LO}	LO input power		0		dBm
LO_leak	LO leakage (1) (2)		-30		dBm
LO_sup	LO cancelation (1) (3)		-65		dBm
IM_rej	Image Rejection (1)		20		dBc
RL_{LO}	LO Input Return Loss (@P_{LO}=0dBm)		-8		dB
RL_{RF}	RF Input Return Loss		-10		dB
OIP3	Output IP3		12		dBm
IMD2	2^{nd} order intermodulation ratio		38		dBc
N	Noise Floor		-156		dBm/Hz
Amp_bal	I/Q Amplitude balance	-1		+1	dB
Ph_err	Quadrature Phase error	-5		+5	°
V_{I_DC}	Baseband I DC voltage differential mode (4)	-0.2		+0.2	V
V_{Q_DC}	Baseband Q DC voltage differential mode (4)	-0.2		+0.2	V
V_{BBI}	Baseband I AC voltage differential mode (5)	-0.8		0.8	V
V_{BBQ}	Baseband Q AC voltage differential mode (5)	-0.8		0.8	V
VDx	DC supply voltage		4		V
VG	Mixer gate bias voltage		-0.7		V
Idq	DC quiescent current		120		mA

(1) Given for F_{BB} = 10MHz and V_{BBI} = V_{BBQ} = 200mV_{pp} (over 50Ω) and P_{LO} = 0dBm
(2) LO leakage without cancelation (i.e. no DC tuning: V_{I_DC} = V_{Q_DC} = 0V)
(3) LO leakage cancelation (i.e. with DC tuning on V_{I_DC} and V_{Q_DC})
(4) Use to cancel LO leakage. Differential mode means I and Ib voltage are opposite. Tuning adjustment are need for each frequency, temperature and LO power.
(5) Peak to Peak Voltage.

These values are representative of onboard measurements as defined on the drawing in paragraph "Evaluation mother board".

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Absolute Maximum Ratings (1)

Tamb.= +25°C

Symbol	Parameter	Values	Unit
VDx	Drain bias voltage	4.5	V
Idq	DC quiescent current	150	mA
VG	Gate bias voltage	-2 to +0.4	V
Tj	Junction temperature	175	°C
Ta	Operating temperature range	-40 to +85	°C
Tstg	Storage temperature range	-55 to +150	°C

(1) Operation of this device above anyone of these parameters may cause permanent damage.

Typical Bias Conditions

Tamb.= +25°C

Symbol	Pad N°	Parameter	Values	Unit
VD1	9	Drain 1 bias voltage	4	V
VD2	10	Drain 2 bias voltage	4	V
VD3	11	Drain 3 bias voltage	4	V
VG	27	Mixer gate bias voltage	-0.7	V

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Device thermal performances

All the figures given in this section are obtained assuming that the QFN device is cooled down only by conduction through the package thermal pad (no convection mode considered). The temperature is monitored at the package back-side interface (Tcase) as shown below.
The system maximum temperature must be adjusted in order to guarantee that Tcase remains below than the maximum value specified in the next table. So, the system PCB must be designed to comply with this requirement.

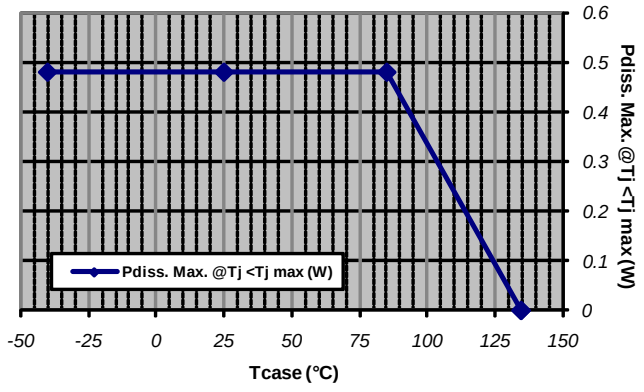
A derating must be applied on the dissipated power if the Tcase temperature cannot be maintained below than the maximum temperature specified (see the curve Pdiss. Max) in order to guarantee the nominal device life time (MTTF).

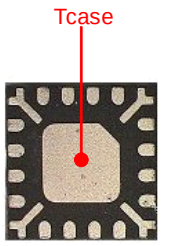
DEVICE THERMAL SPECIFICATION : CHM1481-QFG			
Recommended max. junction temperature (Tj max)	:	134	°C
Junction temperature absolute maximum rating	:	175	°C
Max. continuous dissipated power (Pdiss. Max.)	:	0.5	W
=> Pdiss. Max. derating above Tcase(1)= 85 °C	:	10	mW/°C
Junction-Case thermal resistance (Rth J-C)(2)	:	<103	°C/W
Minimum Tcase operating temperature(3)	:	-40	°C
Maximum Tcase operating temperature(3)	:	85	°C
Minimum storage temperature	:	-55	°C
Maximum storage temperature	:	150	°C

(1) Derating at junction temperature constant = Tj max.

*(2) Rth J-C is calculated for a worst case considering the **hottest junction** of the MMIC and all the devices biased.*

(3) Tcase=Package back side temperature measured under the die-attach-pad (see the drawing below).





Example: QFN 16L 3x3
Location of temeprature reference point (Tcase) on package's bottom side

6.4

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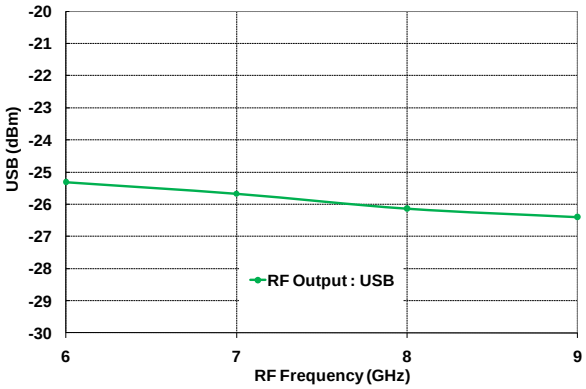
Typical on Board Measurements

Tamb.= +25°C, VD1 = VD2 = VD3 = +4V, Idq = 100mA

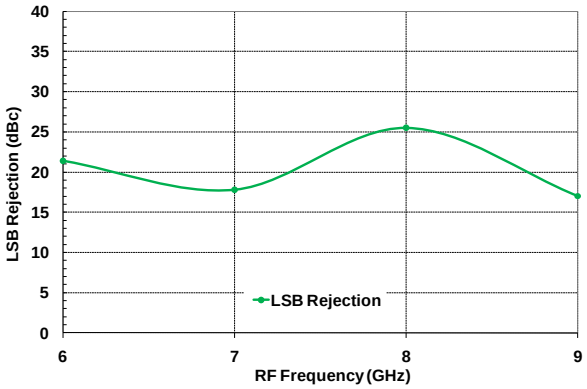
USB versus RF Frequency

F_{BB} = 10MHz / V_{BBI} = V_{BBQ} = 200mVpp
P_{LO} = 0dBm



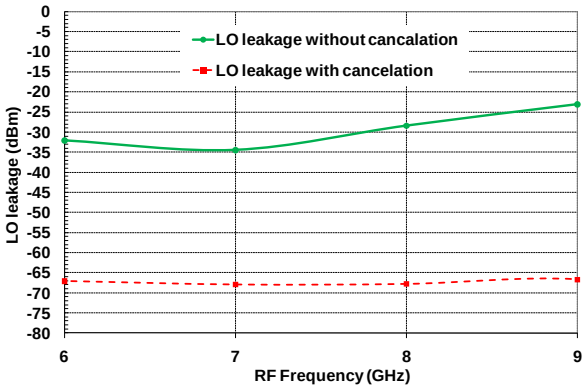
LSB Rejection versus RF Frequency

F_{BB} = 10MHz / V_{BBI} = V_{BBQ} = 200mVpp
P_{LO} = 0dBm



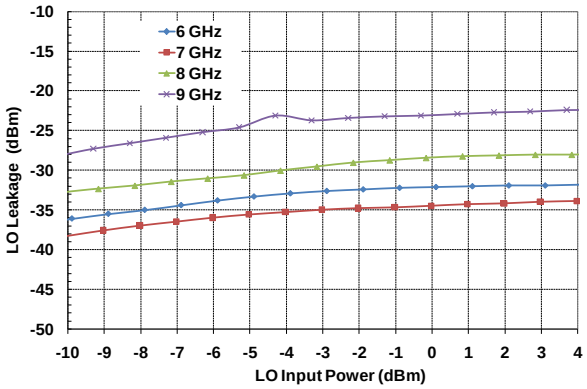
LO leakage versus RF Frequency

F_{BB} = 10MHz / V_{BBI} = V_{BBQ} = 200mVpp
P_{LO} = 0dBm



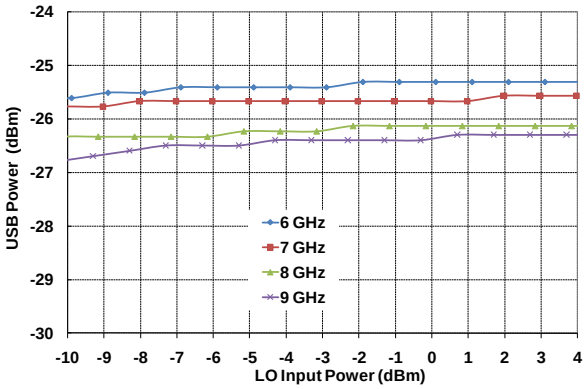
LO leakage versus LO Input Power

F_{BB} = 10MHz / V_{BBI} = V_{BBQ} = 200mVpp
P_{LO} = 0dBm



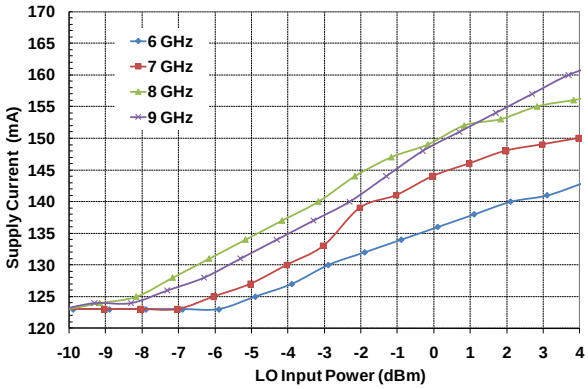
USB versus LO Input Power

F_{BB} = 10MHz / V_{BBI} = V_{BBQ} = 200mVpp
F_{LO}: [6 to 9 / 1] GHz



DC Supply Current versus LO Input Power

F_{BB} = 10MHz / V_{BBI} = V_{BBQ} = 200mVpp
F_{LO}: [6 to 9 / 1] GHz



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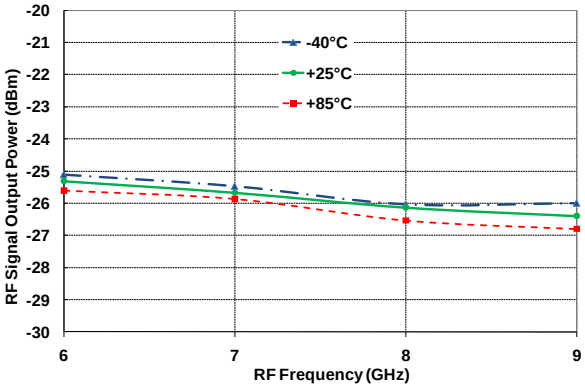
Temperature Board Measurements

VD1 = VD2 = VD3 = +4V, Idq = 100mA

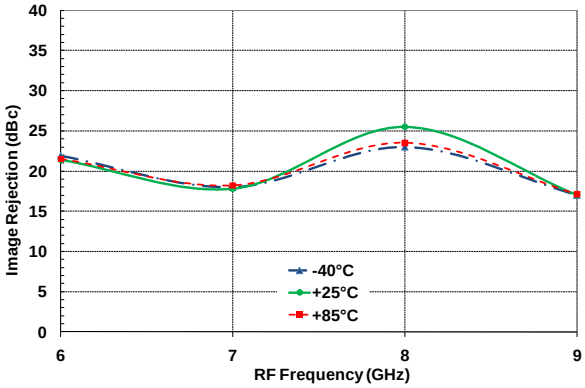
USB versus RF Frequency

F_{BB} = 10MHz / V_{BBI} = V_{BBQ} = 200mVpp
P_{LO} = 0dBm



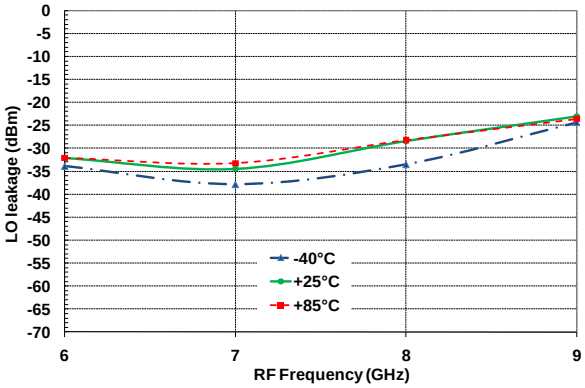
LSB Rejection versus RF Frequency

F_{BB} = 10MHz / V_{BBI} = V_{BBQ} = 200mVpp
P_{LO} = 0dBm



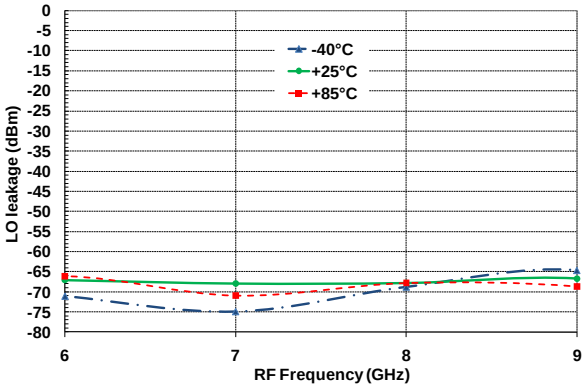
LO leakage versus RF Frequency

F_{BB} = 10MHz / V_{BBI} = V_{BBQ} = 200mVpp
P_{LO} = 0dBm / V_{I_DC} = V_{Q_DC} = 0V



LO cancelation versus RF Frequency

F_{BB} = 10MHz / V_{BBI} = V_{BBQ} = 200mVpp
P_{LO} = 0dBm / V_{I_DC} & V_{Q_DC} tuned



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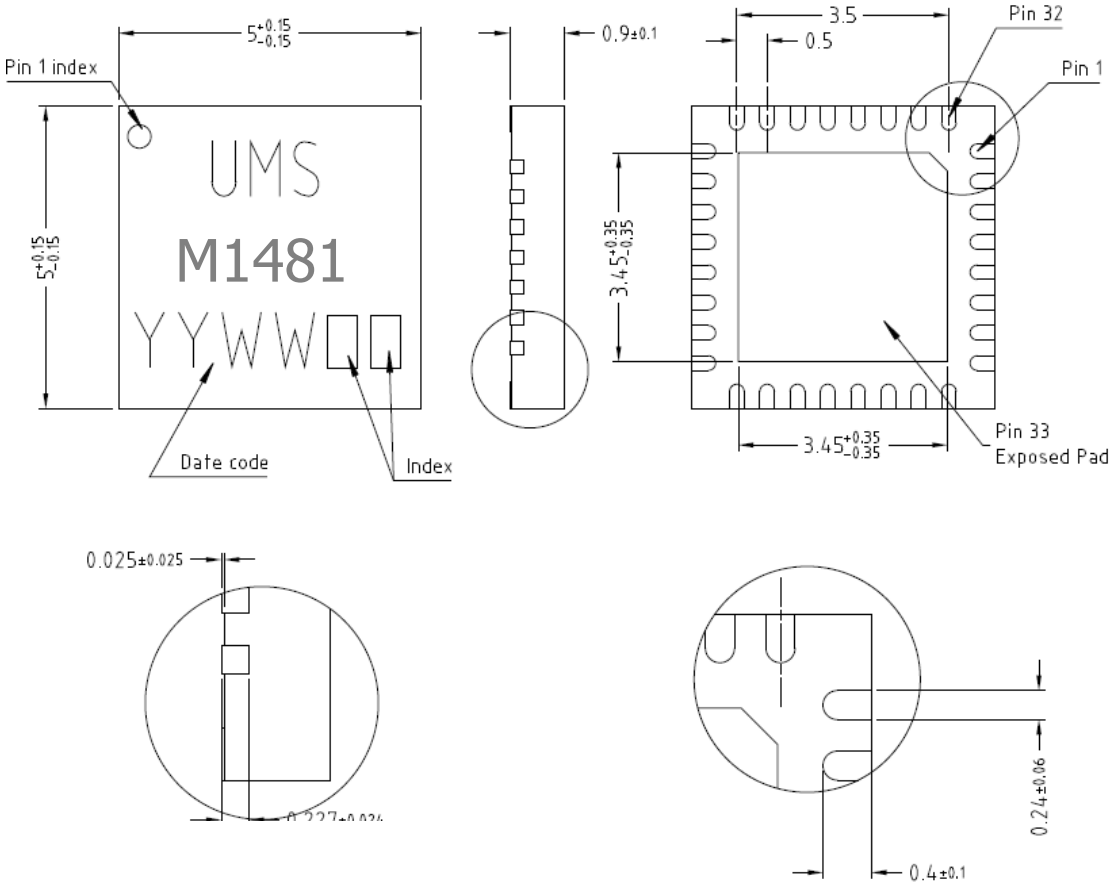
Package outline [1]



Matt tin, Lead Free	(Green)	1- Nc	12- Nc	23- Gnd[2]
Units :	mm	2- Nc	13- Nc	24- Nc
From the standard :	JEDEC MO-220	3- Nc	14- Nc	25- I
	(VHHD)	4- Nc	15- Nc	26- IB
33-	GND	5- Nc	16- Gnd[2]	27- VG
		6- Gnd[2]	17- Nc	28- Nc
		7- LO	18- Nc	29- QB
		8- Gnd[2]	19- Nc	30- Q
		9- VD1	20- Nc	31- Gnd[2]
		10- VD2	21- Gnd[2]	32- Nc
		11- VD3	22- RF	

[1] The package outline drawing included to this data-sheet is given for indication. Refer to the application note AN0017 (http://www.ums-gaas.com) for exact package dimensions.

[2] It is strongly recommended to ground all pins marked “Gnd” through the PCB board. Ensure that the PCB board is designed to provide the best possible ground to the package.

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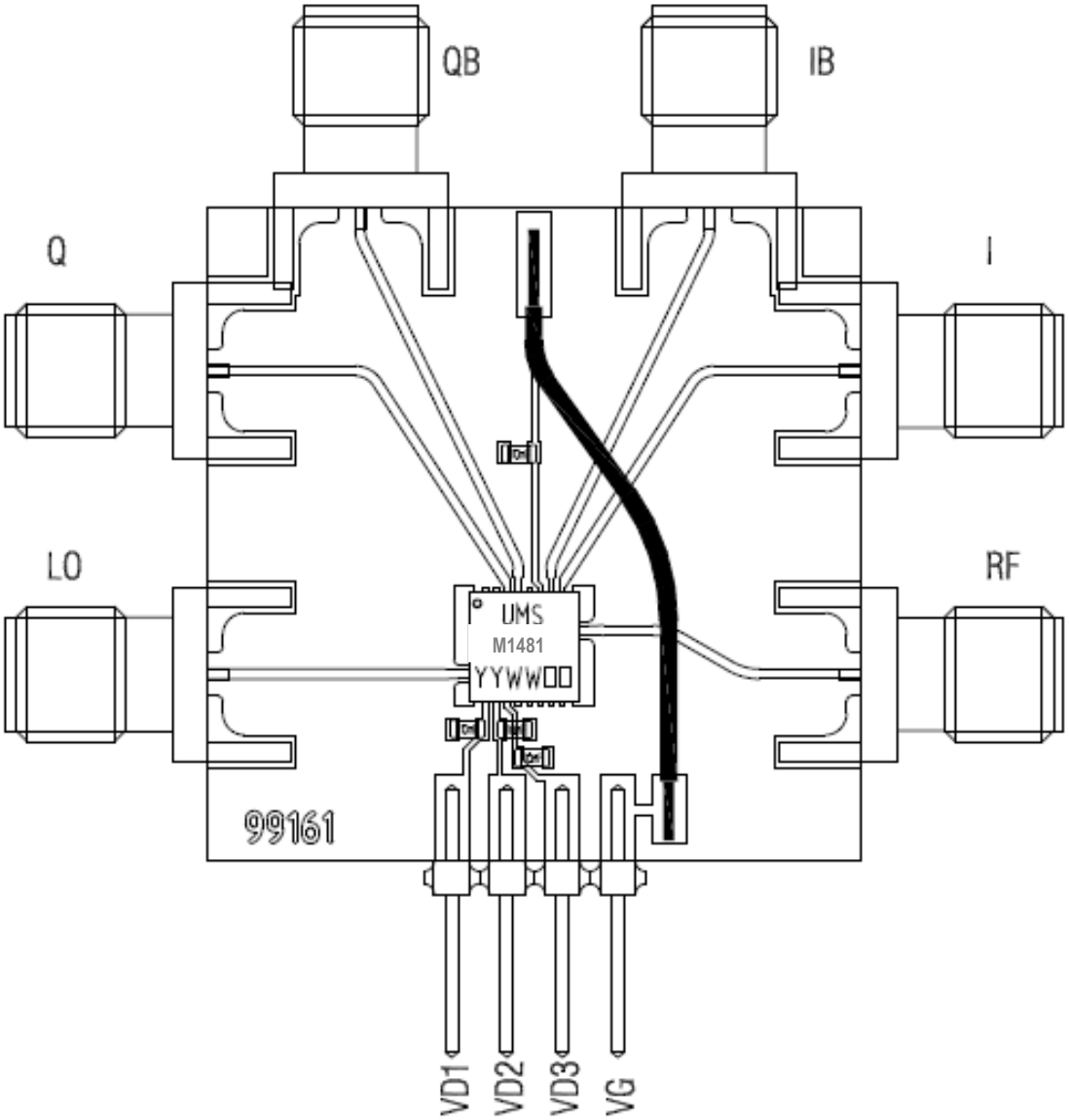
Evaluation mother board

- Compatible with the proposed footprint.
- Based on typically Ro4003 / 8mils or equivalent.
- Using a micro-strip to coplanar transition to access the package.
- Recommended for the implementation of this product on a module board.
- Decoupling capacitors of 10nF ±10% are recommended for all DC accesses.
- See application note AN0017 for details.



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Notes

ESD protections are implemented on LO port, RF port, baseband ports, drain and gate ports.

The DC connections do not include any decoupling capacitor in package, therefore it is mandatory to provide a good external DC decoupling (10nF) on the PC board, as close as possible to the package.

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Recommended package footprint

Refer to the application note AN0017 available at http://www.ums-gaas.com for package foot print recommendations.

SMD mounting procedure

For the mounting process standard techniques involving solder paste and a suitable reflow process can be used. For further details, see application note AN0017.

Recommended environmental management

UMS products are compliant with the regulation in particular with the directives RoHS N°2011/65 and REACh N°1907/2006. More environmental data are available in the application note AN0019 also available at http://www.ums-gaas.com.

Recommended ESD management

Refer to the application note AN0020 available at http://www.ums-gaas.com for ESD sensitivity and handling recommendations for the UMS package products.

Ordering Information

QFN 5x5 RoHS compliant package:	CHM1481-QFG/XY	
	Stick: XY = 20	Tape & reel: XY = 21

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